Shashi Bala

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Design and analysis of electrostatic doped tunnel CNTFET for various process parameters variation. Superlattices and Microstructures, 2018, 124, 160-167.	3.1	27
2	Design and simulation of nanoscale double-gate TFET/tunnel CNTFET. Journal of Semiconductors, 2018, 39, 044001.	3.7	18
3	Design and performance analysis of low-power SRAM based on electrostatically doped tunnel CNTFETs. Journal of Computational Electronics, 2019, 18, 856-863.	2.5	17
4	Electrostatically doped tunnel CNTFET model for low-power VLSI circuit design. Journal of Computational Electronics, 2018, 17, 1528-1535.	2.5	11
5	Study and Analysis of Advanced 3D Multi-Gate Junctionless Transistors. Silicon, 2022, 14, 1053-1067.	3.3	9
6	Improved Sensitivity of Dielectric Modulated Junctionless Transistor for Nanoscale Biosensor Design. Sensor Letters, 2020, 18, 328-333.	0.4	8
7	Comparative Study and Analysis of CNTFET and Tunnel CNTFET. Journal of Nanoelectronics and Optoelectronics, 2018, 13, 324-330.	0.5	7
8	Parameter Variation Analysis of Dopingless and Junctionless Nanotube MOSFET. Silicon, 2022, 14, 5255-5263.	3.3	4
9	Design and Simulation Analysis of NWFET for Digital Application. Advances in Computer and Electrical Engineering Book Series, 2021, , 123-138.	0.3	1
10	CNTFET-Based Memory Design. Advances in Computer and Electrical Engineering Book Series, 2020, , 16-36.	0.3	1
11	Comparative performance analysis of Carbon Nanotube and Si-Nanotube based Field effect Transistors. IOP Conference Series: Materials Science and Engineering, 0, 1033, 012028.	0.6	Ο
12	Comparative Performance Analysis of Nanowire and Nanotube Field Effect Transistors. Advances in Computer and Electrical Engineering Book Series, 2021, , 54-70.	0.3	0
13	Silicon Material Based Tunnel FET for Controlling Ambipolar Current. Silicon, 0, , 1.	3.3	0